



Product data sheet

1. Product profile

1.1 General description

Passivated, sensitive gate triacs in a SOT54 plastic package

1.2 Features

Designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

1.3 Applications

General purpose switching and phase control

1.4 Quick reference data

- V_{DRM} ≤ 600 V (BT131-600)
- V_{DRM} ≤ 800 V (BT131-800)



2. Pinning information

Table 1: Pinning

	5		
Pin	Description	Simplified outline	Symbol
1	main terminal 2 (T2)		NI
2	gate (G)		T2-T1
3	main terminal 1 (T1)		sym051
		SOT54 (TO-92)	



3. Ordering information

Table 2: Ordering information				
Type number	Package			
	Name	Description	Version	
BT131-600	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54	
BT131-800				

4. Limiting values

Table 3: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage				
	BT131-600		<u>[1]</u> _	600	V
	BT131-800		-	800	V
I _{T(RMS)}	RMS on-state current	all conduction angles; T _{lead} = 51.2 °C; see <u>Figure 1</u> , <u>4</u> and <u>5</u>	-	1	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; $T_j = 25 \text{ °C}$ prior to surge; see Figure 2 and <u>3</u>			
		t = 20 ms	-	12.5	А
		t = 16.7 ms	-	13.8	А
l ² t	l ² t for fusing	t = 10 ms	-	1.28	A ² s
dl _T /dt	rate of rise of on-state current	I_{TM} = 1.5 A; I_G = 20 mA; dI _G /dt = 200 mA/µs			
		T2+ G+	-	50	A/μs
		T2+ G-	-	50	A/µs
		T2– G–	-	50	A/μs
		T2– G+	-	10	A/μs
I _{GM}	peak gate current		-	2	А
P _{GM}	peak gate power		-	5	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C
Тj	junction temperature		-	125	°C

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the triac may switch to the on-state. The rate of rise of current should not exceed 3 A/µs.

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5. Thermal characteristics

Table 4:	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	full cycle	-	-	60	K/W
		half cycle	-	-	80	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	see <u>Figure 6</u>	<u>[1]</u> -	150	-	K/W

[1] Mounted on a printed-circuit board; lead length = 4 mm



6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	$V_D = 12 \text{ V}; I_T = 100 \text{ mA}; \text{ see}$ Figure 8				
		T2+ G+	-	0.4	3	mA
		T2+ G–	-	1.3	3	mA
		T2– G–	-	1.4	3	mA
		T2– G+	-	3.8	7	mA
l	latching current	V _D = 12 V; I _{GT} = 100 mA; see <u>Figure 10</u>				
		T2+ G+	-	1.2	5	mA
		T2+ G–	-	4	8	mA
		T2– G–	-	1	5	mA
		T2– G+	-	2.5	8	mA
I _H	holding current	V _D = 12 V; I _{GT} = 100 mA; see <u>Figure 11</u>	-	1.3	5	mA
V _T	on-state voltage	I _T = 1.4 A; see <u>Figure 9</u>	-	1.2	1.5	V
V _{GT}	gate trigger voltage	$I_T = 10 \text{ mA}$; gate open circuit; see Figure 7				
		V _D = 12 V; I _{GT} = 100 mA	-	0.7	1.5	V
		V _D = 400 V; I _{GT} = 100 mA; T _j = 125 °C	0.2	0.3	-	V
I _D	off-state current	$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	-	0.1	0.5	mA
Dynamic c	haracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 67 % $V_{DRM(max)}$; T_j = 125 °C; exponential waveform; R_{GK} = 1 k Ω ; see <u>Figure 12</u>	10	20	-	V/µs
dV _{com} /dt	rate of change of commutating current	$V_{DM} = 400 \text{ V}; \text{ T}_{j} = 125 \text{ °C};$ $dI_{com}/dt = 0.5 \text{ A/ms}$	2	-	-	V/µs
t _{gt}	gate-controlled turn-on time	$I_{TM} = 1.5 \text{ A}; V_D = V_{DRM(max)};$ $I_G = 100 \text{ mA}; \text{ dI}_G/\text{dt} = 5 \text{ A}/\mu\text{s}$	-	2	-	μs

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7. Package information

Epoxy meets requirements of UL94 V-0 at 1/8 inch.



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8. Package outline



Fig 13. Package outline SOT54 (TO-92)

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9. Revision history

Table 6: Revisio	on history				
Document ID	Release date	Data sheet status	Change notice	Doc. number	Supersedes
BT131_SER_8	20050909	Product data sheet	-	-	BT131_SER_7
Modifications:		it of this data sheet has n standard of Philips Se corrected	•	comply with the ne	ew presentation and
BT131_SER_7	20040101	Product specification	-	-	BT131_SER_6
BT131_SER_6	20030801	Product specification	-	-	BT131_SER_5
BT131_SER_5	20001201	Product specification	-	-	BT131_SER_4
BT131_SER_4	20000501	Product specification	-	-	BT131_SER_3
BT131_SER_3	19980401	Product specification	-	-	-

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10. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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